





HIGH-VOLTAGE, LOW-SENSITIVITY AUTOMOTIVE HALL-EFFECT LATCH

Description

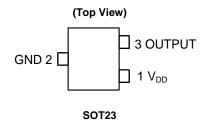
The AH3768Q is an AEC-Q100 qualified, high-voltage, low-sensitivity Hall-Effect latch IC designed for brushless DC-motor commutation, speed measurement, angular or linear encoders and position sensors in automotive applications. To support wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3768Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an over current limit and a Zener clamp.

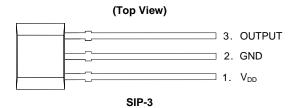
The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (B_{op}) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point (B_{rp}).

Features

- Bipolar Latch Operation (South Pole: On, North Pole: off)
- High Sensitivity: B_{op} and B_{rp} of +175G and -175G Typical
- Single, Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- · Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM >8kV, CDM: >2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SOT23 and SIP-3 Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments





Applications

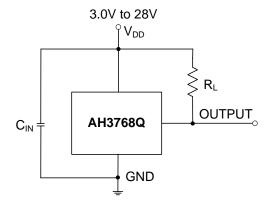
- · Brushless DC-Motor Commutation
- Revolution Per Minute (RPM) Measurement
- · Angular and Linear Encoder and Position Sensing and Indexing
- Flow Meters
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Automotive Applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



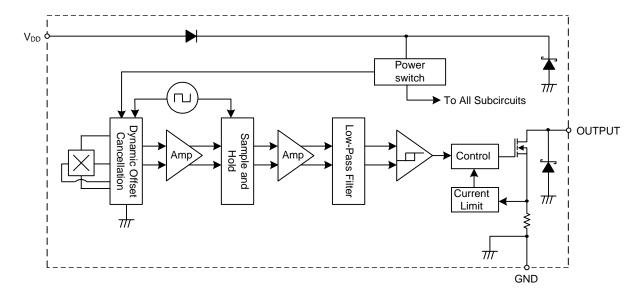
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R_L is the pull-up resistor.

Pin Descriptions

Package: SOT23 and SIP-3

Pin Number	Pin Name	Function			
1	V_{DD}	Power Supply Input			
2	GND	Ground			
3	OUTPUT	Output Pin			

Functional Block Diagram



July 2015



Absolute Maximum Ratings (Notes 5 & 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
V_{DD}	Supply Voltage (Note 6)		32	V	
V_{DDR}	Reverse Supply Voltage (Note 6)	-32	V		
V _{OUT_MAX}	Output Off Voltage (Note 6)	32	V		
I _{OUT}	Continuous Output Current		60	mA	
I _{OUT_R}	Reverse Output Current	-50	mA		
В	Magnetic Flux Density	Unlimited			
Б	Package Power Dissinction	SIP-3	550	m1/1/	
P _D	Package Power Dissipation	SOT23	230	mW	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand - Human Body Model (HME	8	kV		
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)		800	V	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model (C	DM)	2	kV	

Notes:

Recommended Operating Conditions (@T_A = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Parameter Conditions			
V_{DD}	Supply Voltage	Operating	3.0 to 28	V	
T _A	Operating Temperature Range	Operating	-40 to +150	°C	

Electrical Characteristics (Notes 7 & 8) (@T_A = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout_on	Output On Voltage	$I_{OUT} = 20\text{mA}, B > B_{op}$	-	0.2	0.4	V
I _{LKG}	Output Leakage Current (when output is off)	V _{OUT} = 28V, B < B _{rp} , Output off	1	<0.1	10	μΑ
I_{DD}	Supply Current	Output open, T _A = +25°C	-	3	3.5	mA
		Output open, T _A = -40°C to +150°C	-	-	4	mA
		$V_{DD} = -18V, T_A = +25^{\circ}C$	1	0.6	-	μΑ
loo o	Boyorga Supply Current	$V_{DD} = -18V$, $T_A = -40$ °C to $+150$ °C	-	0.6	1,500	μΑ
I _{DD_R}	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	-	μA
		$V_{DD} = -28V$, $T_A = -40^{\circ}C$ to $+150^{\circ}C$	-	1.6	2,500	μA
t _{P_ON}	Device Power-On Time (start-up time)	$V_{DD} >= 3V, B > B_{op} (Note 7)$	-	10		μs
f _c	Chopping Frequency	V _{DD} >= 3V	-	800	-	kHz
t _d	Response Time Delay (time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	-	3.75	-	μs
t _r	Output Rising Time (external pull-up resistor R _L and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	1	0.2	1	μs
t _f	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$, $C_L = 20pF$	-	0.1	1	μs
locL	Output Current Limit	B > B _{op} , (Note 10)	30	-	55	mA
V_Z	Zener Clamp Voltage	$I_{DD} = 5mA$	28	-	-	V

Notes:

^{5.} Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

^{6.} The absolute maximum VDD of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

^{7.} When power is initially turned on, Voo must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

^{8.} Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

^{9.} Guaranteed by design, process control and characterization. Not tested in production.

^{10.} The device will limit the output current IOUT to current limit of IOCL.



$\textbf{Magnetic Characteristics} \text{ (Notes 11 & 12) (T}_{A} = -40^{\circ}\text{C to } + 150^{\circ}\text{C}, \text{ V}_{DD} = 3.0\text{V to 28V, unless otherwise specified)}$

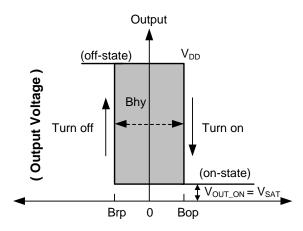
(1mT=10 Gauss)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
B _{ops} (South pole to part marking side for	Operation Point	V _{DD} = 12V, T _A = +25°C	-	175	-		
SOT23 and SIP-3 packages)	Operation 1 ont	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	140	175	200		
B _{rps} (North pole to part marking side for	Release Point	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	-175	1	Gauss	
SOT23 and SIP-3 packages)	Release Follit	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-200	-175	-140	Gauss	
D (D D)	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	350	-		
B_{hy} ($ B_{opx} $ - $ B_{rpx} $)	Tiyoteresis (Note 13)	$T_A = -40^{\circ}\text{C to } +150^{\circ}\text{C}$	280	350	400		

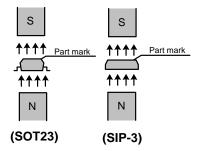
Notes:

- 11. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



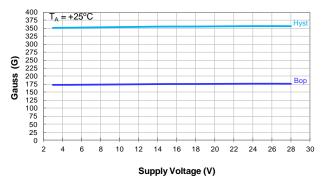
(Magnetic Flux Density B)



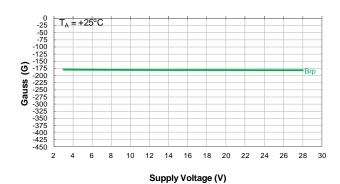


Typical Operating Characteristics

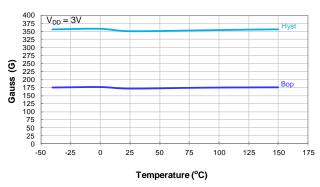
Output Switch Operate and Release Points (Magnetic Thresholds) – B_{op} and B_{rp}



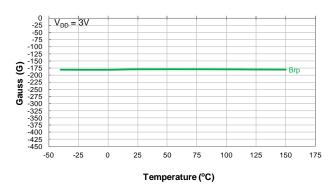
Switch Operate Point Bop vs Supply Voltage



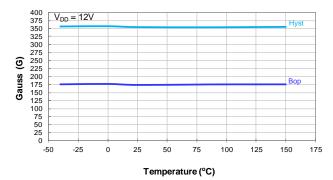
Switch Release Point Brp vs Supply Voltage



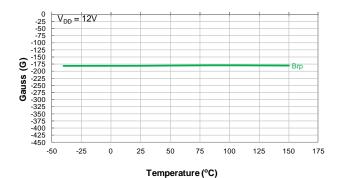
Switch Operate Point Bop vs Temperature



Switch Release Point Brp vs Temperature



Switch Operate Point Bop vs Temperature

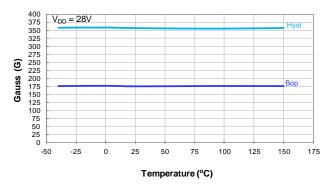


Switch Release Point Brp vs Temperature

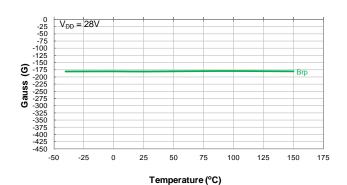


Typical Operating Characteristics

Output Switch Operate and Release Points (Magnetic Thresholds) – B_{op} and B_{rp} (cont.)

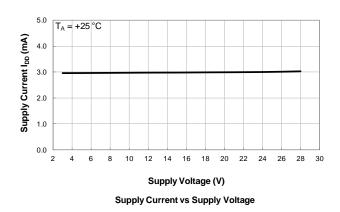


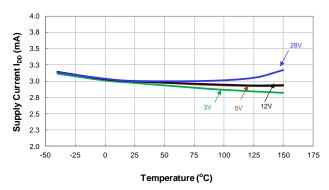
Switch Operate Point Bop vs Temperature



Switch Release Point Brp vs Temperature

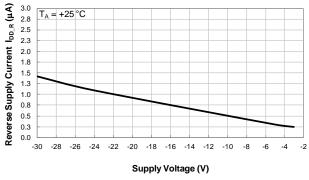
Supply Current



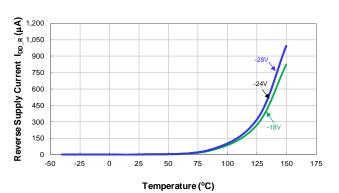


Supply Current vs Temperature

Reverse Supply Current



Reverse Supply Current vs Supply Voltage

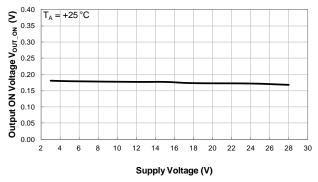


Reverse Supply Current vs Temperature

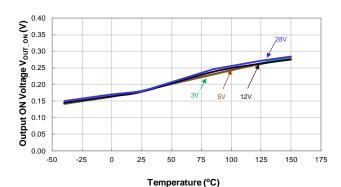


Typical Operating Characteristics (cont.)

Output Switch On Voltage

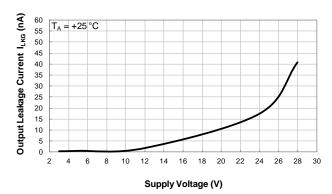


Output ON Voltage vs Supply Voltage

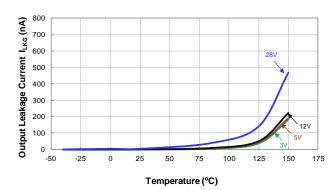


Output ON Voltage vs Temperature

Output Switch Leakage Current

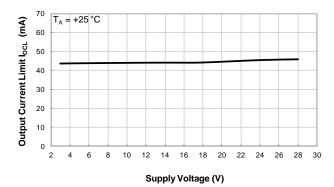


Output Leakage Current vs Supply Voltage

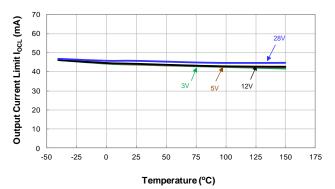


Output Leakage Current vs Temperature

Output Current Limit



Output Current Limit vs Supply Voltage



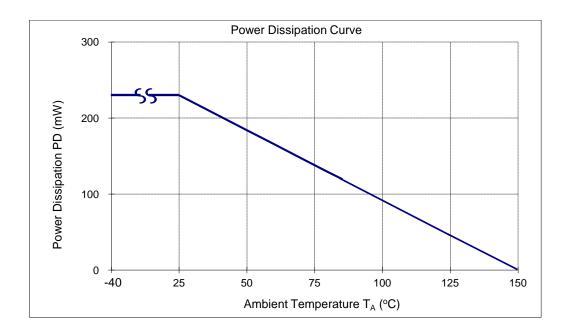
Output Current Limit vs Temperature



Thermal Performance Characteristics

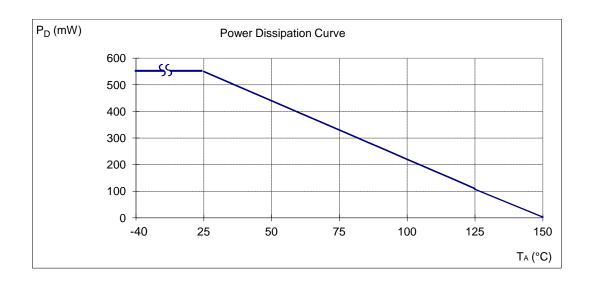
(1) Package type: SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



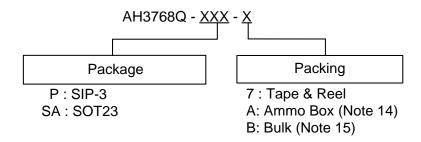
(2) Package type: SIP-3

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information



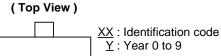
	Dookogo		Е	Bulk 7" Tape and		Bulk 7" Tape and Reel		d Reel	Ammo Box	
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix		
AH3768Q-P-A	Р	SIP-3	NA	NA	NA	NA	4,000/Box	-A		
AH3768Q-P-B	Р	SIP-3	1,000	-B	NA	NA	NA	NA		
AH3768Q-SA-7	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA		

Notes: 14. An

- 14. Ammo Box is for SIP-3 Spread Lead.
- 15. Bulk is for SIP-3 Straight Lead.

Marking Information

(1) Package Type: SOT23



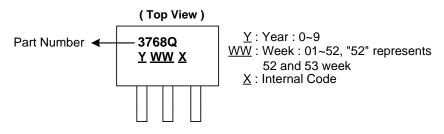
XX Y W X

 $\frac{W}{}: \text{Week}: \text{A to Z}: \text{1 to 26 week}; \\ \text{a to z}: \text{27 to 52 week}; \text{z represents} \\ \text{52 and 53 week}$

X : Internal code

Part Number	Package	Identification Code
AH3768Q	SOT23	WT

(2) Package Type: SIP-3



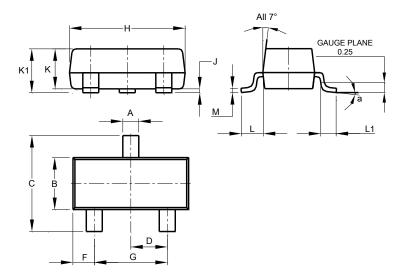
Part Number	Package	Identification Code
AH3768Q	SIP-3	3768Q



Package Outline Dimensions (All dimensions in mm.)

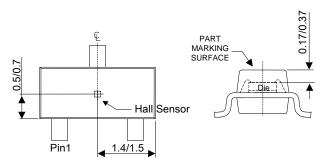
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Ι	2.80	3.00	2.90
7	0.013	0.10	0.05
K	0.890	1.00	0.975
K 1	0.903	1.10	1.025
٦	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а		8°	
All	Dimens	ions in	mm

Min/Max



Sensor Location - To be updated

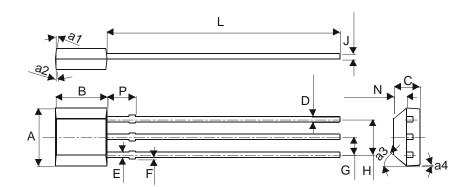


Package Outline Dimensions (cont.) (All dimensions in mm.)

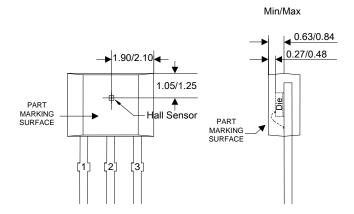
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(2) Package Type: SIP-3 Bulk

Sensor location to be added



;	SIP-3 (Bu	lk)
Dim	Min	Max
Α	3.9	4.3
a1	5°	Тур
a2	5°	Тур
а3	45°	[°] Typ
a4	3°	Тур
В	2.8	3.2
С	1.40	1.60
D	0.33	0.432
Е	0.40	0.508
F	0	0.2
G	1.24	1.30
Н	2.51	2.57
J	0.35	0.43
L	14.0	15.0
N	0.63	0.84
Р	1.55	-
All Di	mension	s in mm



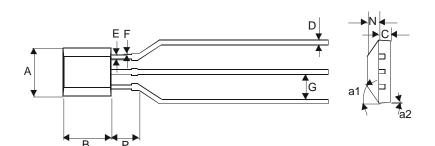
Sensor Location - To be updated



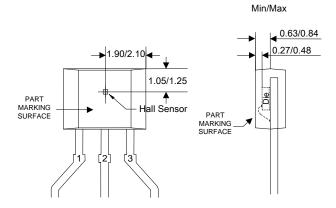
Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(3) Package Type: SIP-3 Ammo Pack



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Typ	
В	2.8	3.2
C	1.40	1.60
D	0.35	0.41
Е	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	-
All Dimensions in mm		

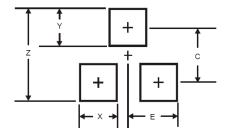


Sensor Location - To be updated

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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